



JT05N065RAD

主要参数 MAIN CHARACTERISTICS

Ic	5 A
VCEs	650V
Vcesat-typ (Vge=15V)	1.7V

用途

- 逆变器
- PDP
- UPS 电源
- 电机控制

APPLICATIONS

- General purpose inverters
- PDP
- UPS
- Motor Control

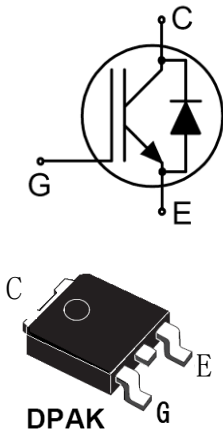
产品特性

- 低栅极电荷
- FS 技术,
- RoHS 产品

FEATURES

- Low gate charge
- FS Technology,
- RoHS product

封装 Package



订货信息 ORDER MESSAGE

订 货 型 号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Non halogen-Tube	有卤-编带 Halogen-Reel	无卤-编带 Non halogen-Reel		
JT05N065RAD-R-B	JT05N065RAD-R-BR	JT05N065RAD-R-A	JT05N065RAD-R-AR	JT05N065RAD	DPAK

绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^{\circ}\text{C}$)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
最高集电极—发射极直流电压 Collector-Emmitter Voltage	V_{CES}	650	V
*连续集电极电流 Collector Current-continuous	I_C	10 ($T=25^{\circ}\text{C}$)	A
		5($T=100^{\circ}\text{C}$)	A
最大脉冲集电极极电流 (注 1) Collector Current – pulse (note 1)	I_{CM}	20	A
最高栅极发射极电压 Gate-Emmitter Voltage	V_{GES}	± 30	V
安全工作区电流 Turn-off safe area	-	20	A
耗散功率 Power Dissipation	P_D $T_c=25^{\circ}\text{C}$	59.5	W
最高结温及存储温度 Operating and Storage Temperature Range	T_J, T_{STG}	$-55 \sim +150$	$^{\circ}\text{C}$
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T_L	300	$^{\circ}\text{C}$

*连续集电极电流由最高结温限制

*Collector current limited by maximum junction temperature





电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单 位 Units
关态特性 Off –Characteristics						
集电极-发射极击穿电压 Collector-Emmitter Voltage	BV_{CES}	$I_C=250\mu A, V_{GE}=0V$	650	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{CES}/\Delta T_J$	$I_C=1mA$, referenced to $25^\circ C$	-	0.5	-	$V/^\circ C$
零栅压下集电极漏电流 Zero Gate Voltage Collector Current	I_{CES}	$V_{CE}=650V, V_{GE}=0V, T_C=25^\circ C$	-	-	10	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GESF}	$V_{CE}=0V, V_{GE}=20V$	-	-	200	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GESR}	$V_{CE}=0V, V_{GE}=-20V$	-	-	-200	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}, I_C=250\mu A$	4.5	-	6.5	V
饱和压降 Collector-Emmitter saturation Voltage	V_{CESAT}	$V_{GE}=15V, I_C=5A, T_C=25^\circ C$	-	1.7	2.05	V
动态特性 Dynamic Characteristics						
输入电容 Input capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V, f=1.0MHz$	-	289	-	pF
输出电容 Output capacitance	C_{oes}		-	32.7	-	pF
反向传输电容 Reverse transfer capacitance	C_{res}		-	7.4	-	pF
栅极电荷总量 Total Gate Charge	Q_g	$V_{CC}=400V, I_C=5A, R_G=10\Omega, V_{GE}=15V, T_C=25^\circ C$	-	11.8	-	nC
栅极-发射极电荷 Gate to emitter charge	Q_{ge}		-	2.57	-	
栅极-集电极电荷 Gate to collector charge	Q_{gc}		-	5.1	-	
栅极电阻-Gate resistance	R_g	$f=1 MHz$, open collector	-	1.6	-	Ω
短路电流-short current	I_{SC}	$V_{GE}=15V, V_{CE}=400V$	-	30	-	A





电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单 位 Units
开启延迟时间 Turn-On delay time	t _d (on)	V _{CC} =400V,I _c =5A,R _G =60Ω V _{GE} =15 V T _C =25℃	-	22	-	ns
上升时间 Turn-On rise time	t _r		-	13	-	ns
关断延迟时间 Turn-Off delay time	t _d (off)		-	91	-	ns
下降时间 Turn-Off Fall time	t _f		-	25	-	ns
开通损耗 Turn-On energy	E _{on}		-	123	-	μ J
关断损耗 Turn-off energy	E _{off}		-	53	-	μ J
总开关损耗 Total switching energy	E _{tot}		-	176	-	μ J
反并联二极管特性及最大额定值 Anti-Parallel Diode Characteristics and Maximum Ratings						
正向压降 Drain-Source Diode Forward Voltage	V _F	V _{GE} =0V, I _F =5A	-	1.5	2.2	V
反向恢复时间 Diode Reverse recovery time	t _{rr}	V _{GE} =0V, V _R =400V I _F =5A dI _F /dt=200A/μs	-	33	-	ns
反向恢复电荷 Diode Reverse recovery charge	Q _{rr}		-	145	-	nC
反向恢复电流 Diode Reverse recovery Current	I _{R_{RM}}		-	2.7	-	A

项 目 Parameter	符 号 Symbol	MAX	单 位 Unit
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	2.1	$^\circ C/W$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	110	$^\circ C/W$

注释:

1: 脉冲宽度由最高结温限制

Notes:

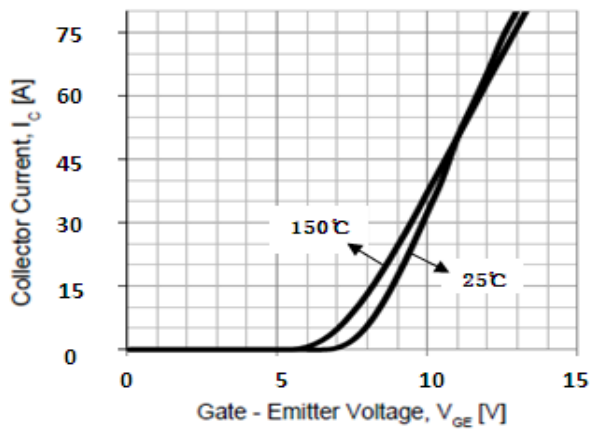
1: Pulse width limited by maximum junction temperature



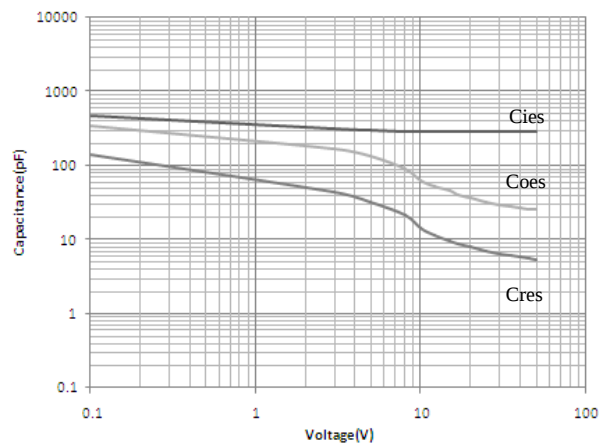


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

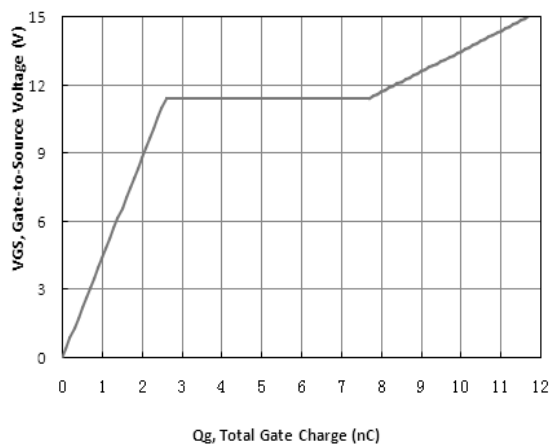
Typical Transfer Characteristics



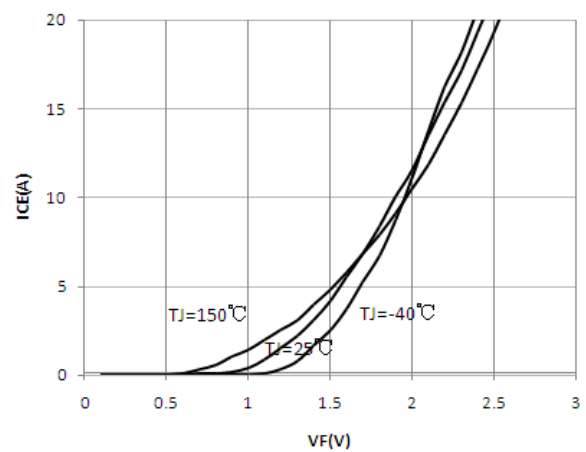
Capacitance Characteristics



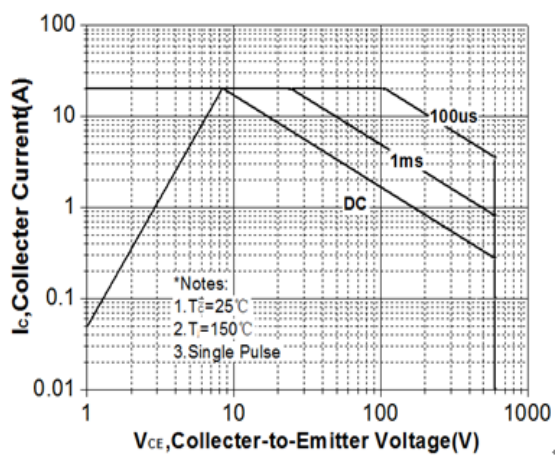
Gate Charge Characteristics



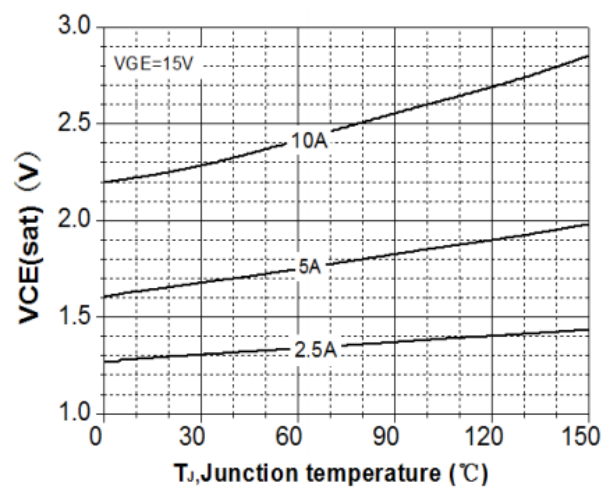
VF vs. Case Temperature at Variant Current Level

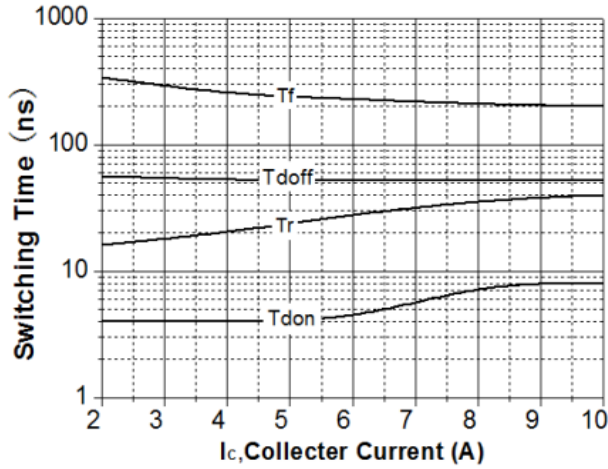
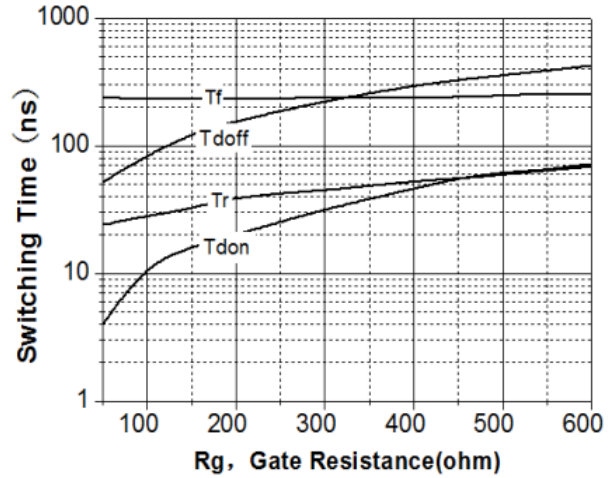
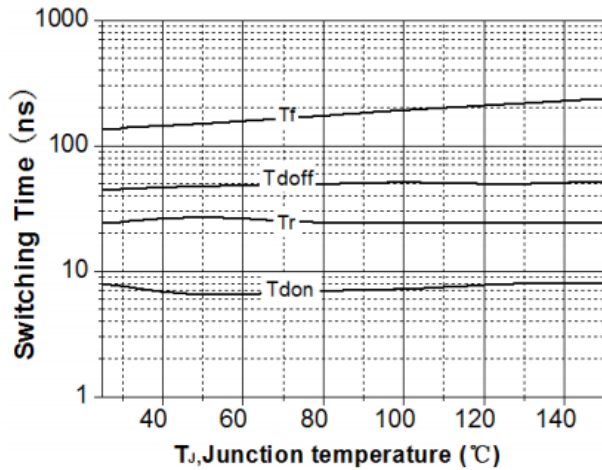
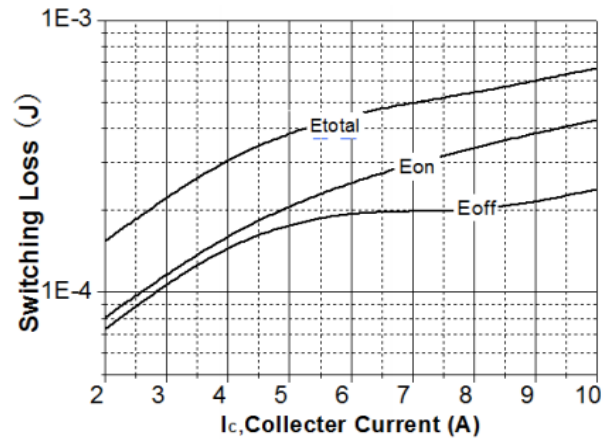
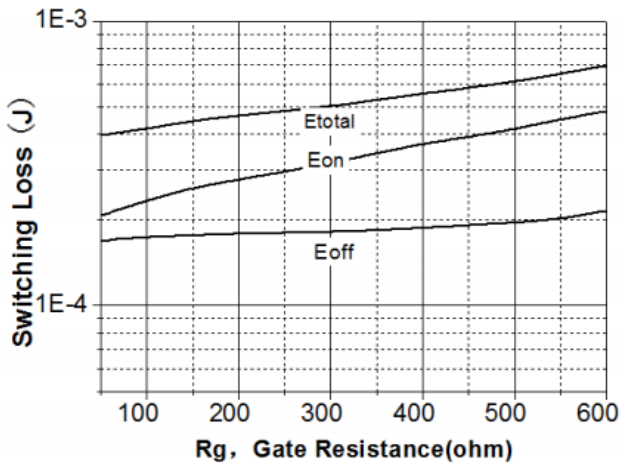
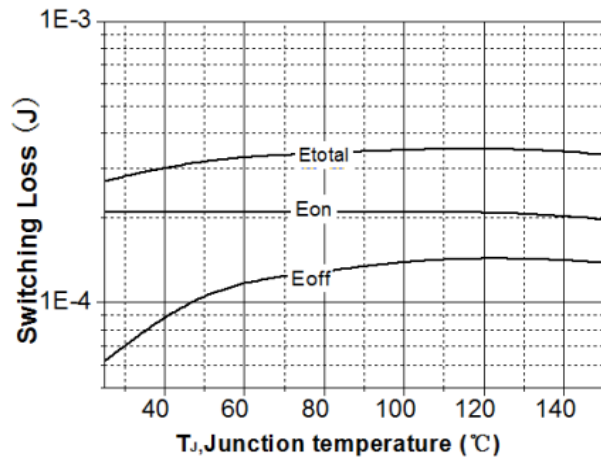


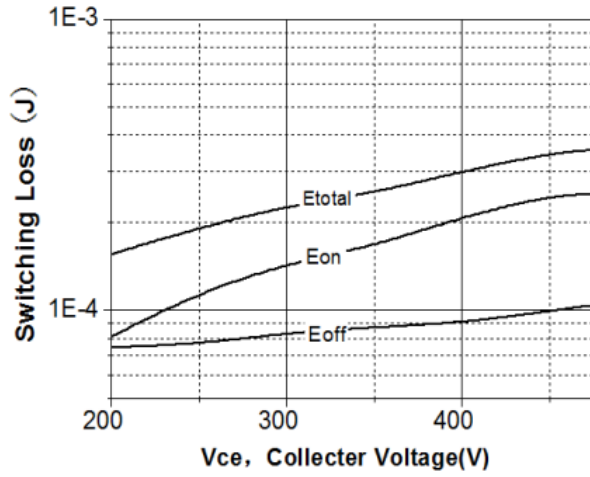
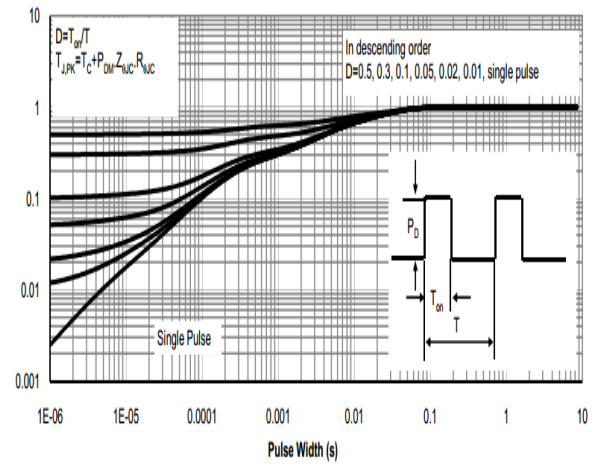
SOA Characteristics For DPAK



Vcesat vs Tj



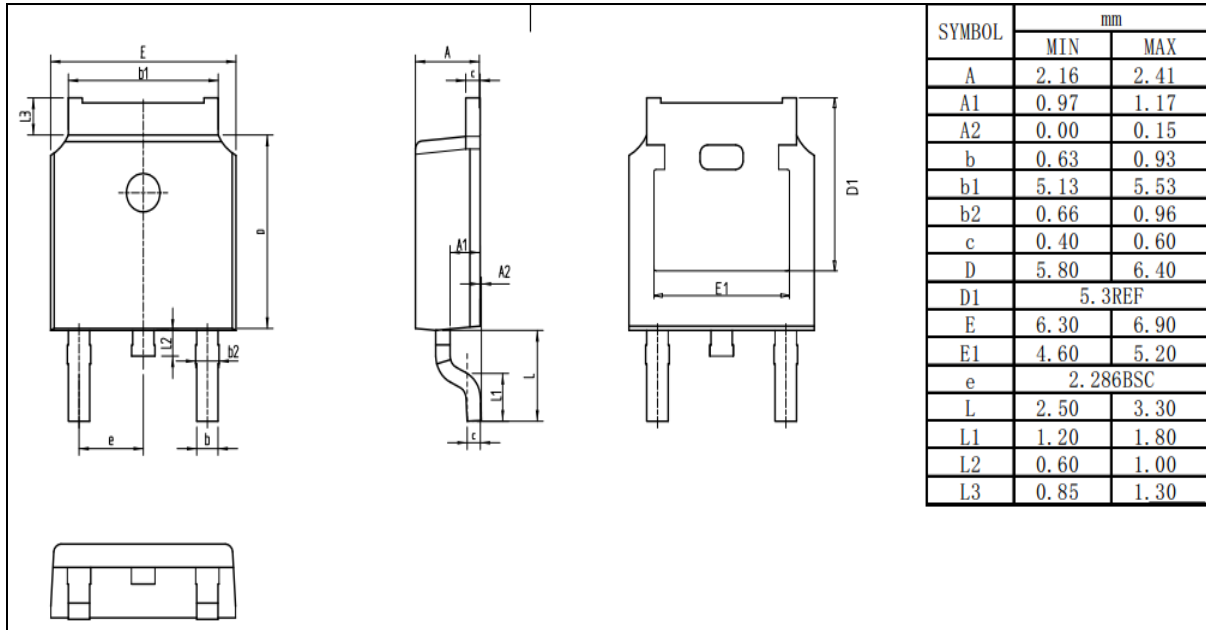
Switching Time vs I_c $T_j=150^{\circ}\text{C}$, $V_{ge}=15\text{V}$, $V_{ce}=400\text{V}$, $R_g=60\ \Omega$ Switching Time vs R_g $T_j=150^{\circ}\text{C}$, $V_{ge}=15\text{V}$, $V_{ce}=400\text{V}$, $I_c=5\text{A}$ Switching Time vs T_j $V_{ge}=15\text{V}$, $V_{ce}=400\text{V}$, $R_g=60\ \Omega$, $I_c=5\text{A}$ Switching Loss vs I_c $T_j=150^{\circ}\text{C}$, $V_{ge}=15\text{V}$, $V_{ce}=400\text{V}$, $R_g=60\ \Omega$ Switching Loss vs R_g $T_j=150^{\circ}\text{C}$, $V_{ge}=15\text{V}$, $V_{ce}=400\text{V}$, $I_c=5\text{A}$ Switching Loss vs T_j $V_{ge}=15\text{V}$, $V_{ce}=400\text{V}$, $I_c=5\text{A}$, $R_g=60\ \Omega$ 

**Switching Loss vs Vce** $T_j=150^{\circ}\text{C}$, $V_{ge}=15\text{V}$, $I_c=5\text{A}$, $R_g=60\ \Omega$ **Transient Thermal Impedance**



外形尺寸 PACKAGE MECHANICAL DATA
DPAK

单位 Unit : mm





注意事项

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